

Facing thermal issues in electronic devices? Efficient Cooling with "Thermalnite®"

 **U-MAP** Co., Ltd.
Ultimate Material and Processing

Company Overview

U-MAP Co., Ltd. is a Nagoya University(Japan)-originated startup developing advanced thermal interface materials to solve heat challenges in electronic devices. By leveraging our proprietary filler Thermalnite®, we deliver innovative thermal management solutions for high-heat applications such as EVs and data centers.

Our Business

Business Area	Description
Thermalnite®	- Development & manufacturing of fibrous AlN filler "Thermalnite®" - Hybrid design with spherical fillers - Support from prototyping to evaluation
Thermal Sheet	- High thermal conductivity, low thermal resistance silicone-based sheets - Ultra-thin models (0.1 mm) available
Ceramics Substrate	- High thermal conductivity, high-strength aluminum nitride (AlN) substrates



Thermalnite®

Fibrous aluminum nitride (AlN)
single crystal

Technology

● Core Technology & Value

Thermalnite®

• Fibrous aluminum nitride (AlN) single crystal filler
✓ Forms efficient thermal paths with minimal loading
✓ Enhances both thermal conductivity and mechanical strength
✓ Boosts performance of polymers and ceramics

● Thermalnite®-Enhanced Products

High-Strength AlN Substrate

• **High Thermal Conductivity & High Strength**

Columnar structure overcomes conventional weaknesses

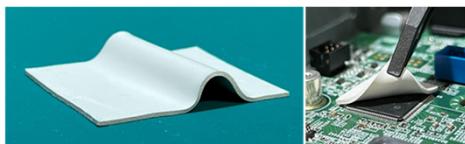


- Thermalnite® enables columnar crystal structure
- Improved strength, suppresses cracking/chipping
- Combines 230 W/m·K thermal conductivity with high durability

High Thermal Conductivity Sheet

• **Top-Class Thermal Conductivity with Flexibility**

Balanced through precisely engineered filler formulation

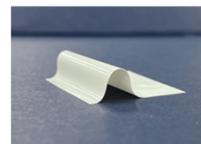


- Thermal conductivity: 10.0 W/(m·K)
- Excellent flexibility for absorbing part tolerances
- Oil-free to maintain electronic component performance

Low Thermal Resistance Sheet

• **Ultra-Low Thermal Resistance & Ultra-Thin**

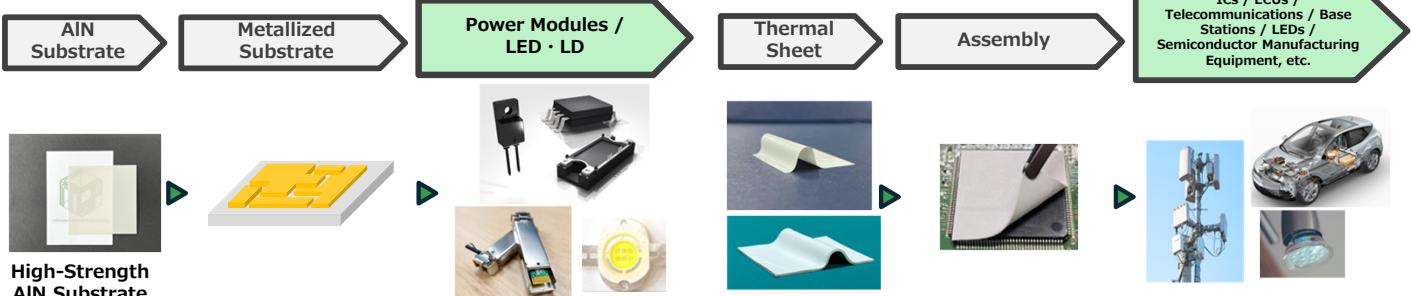
High strength enables 0.1 mm thickness



- 15% lower thermal resistance (industry-leading class)
- 0.1 mm thin & highly insulating
- 4x stronger mechanical strength than conventional materials

Application

Target Applications



High-Strength AlN Substrate

Tokai Open Innovation Complex (TOIC), Chikusa-ku, Nagoya, Japan
Email: pres.office@umap-corp.com

Contact
U-MAP Co., Ltd.

